NSN 5962-01-254-2231

Memory Microcircuit - Page 1 of 1



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Body Length:

- 1.600 inches
- **Body Width:**
- 0.550 inches

Body Height:

0.150 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-0.0/+70.0 degrees celsius

Storage Tempurature Range:

-55.0/+125.0 degrees celsius

Features Provided:

3-state output and w/enable and w/inhibit

Inclosure Material:

Plastic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

N-type metal oxide-semiconductor logic

Input Circuit Pattern:

15 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-1.0 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

250.00 nanoseconds propagation delay time, low to high level output and 250.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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